



P-Channel 20-V (D-S) MOSFET

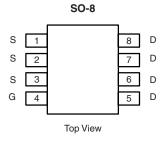
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
- 20	0.040 at V _{GS} = - 4.5 V	- 6.2			
	0.060 at V _{GS} = - 2.7 V	- 5.0			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- Compliant to RoHS Directive 2002/95/EC

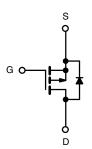


FREE



Ordering Information: Si9433BDY-T1-E3 (Lead (Pb)-free)

Si9433BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise n	noted		_	
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 12			
Ocation	T _A = 25 °C	- I _D	- 6.2	- 4.5	۸	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 5.0	- 3.5		
Pulsed Drain Current		I _{DM}	- 20		Α	
Continuous Source Current (Diode Conduction) ^a	I _S	- 2.3	- 1.2			
	T _A = 25 °C	В	2.5 1.3		W	
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	1.6	0.8	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maniana baratian ta Ambianta	t ≤ 10 s	R _{thJA}	45	50	
Maximum Junction-to-Ambient ^a	Steady State	' ¹thJA	80	95	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	20	24	

Notes

a. Surface Mounted on FR4 board, $t \le 10 \text{ s.}$

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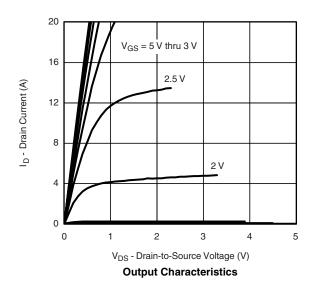
SPECIFICATIONS T _J = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions		Typ. ^a	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 0.6		- 1.5	٧
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA
Zava Cata Valtaga Drain Current	1	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 70 °C			- 10	
0 0: 1 D : 0 1b	1	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$ - 20				Α
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -2.7 \text{ V}$	- 5			А
D : 0	$V_{GS} = -4.5 \text{ V}, I_D = -6.2 \text{ A}$	V _{GS} = - 4.5 V, I _D = - 6.2 A		0.030	0.040	Ω
Drain-Source On-State Resistance ^b	R _{DS(on)}	$V_{GS} = -2.7 \text{ V}, I_D = -5.0 \text{ A}$		0.050	0.060	
Forward Transconductance ^b	9 _{fs}	V _{DS} = - 9 V, I _D = - 6.2 A		15		S
Diode Forward Voltage ^b	V_{SD}	I _S = - 2.6 A, V _{GS} = 0 V		- 0.76	- 1.1	V
Dynamic ^a						
Total Gate Charge	Q_g			8.8	14	
Gate-Source Charge	Q_{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -6.2 \text{ A}$		1.8		nC
Gate-Drain Charge	Q_{gd}			2.4		
Gate Resistance	R_g			8.5		Ω
Turn-On Delay Time	t _{d(on)}			40	60	
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		55	85	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		65	100	ns
Fall Time	t _f			30	45	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.3 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$		35	55	

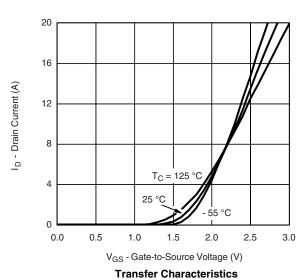
Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



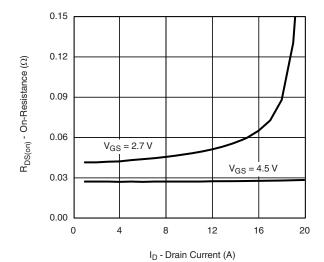




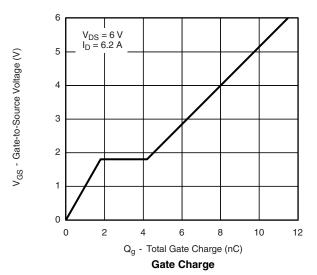


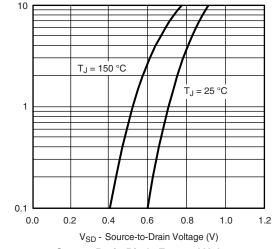


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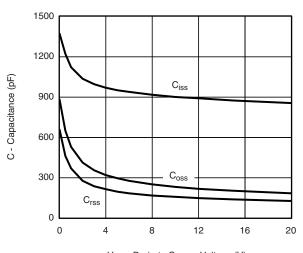


On-Resistance vs. Drain Current



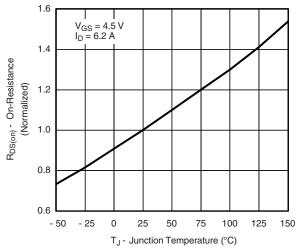


Source-Drain Diode Forward Voltage

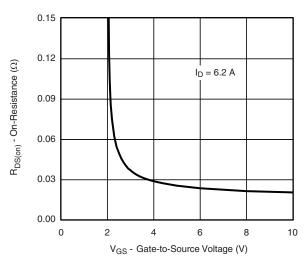


V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature



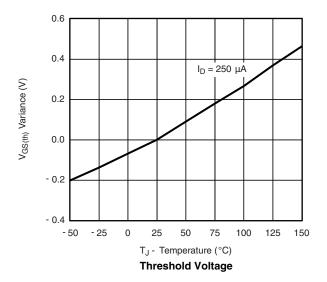
On-Resistance vs. Gate-to-Source Voltage

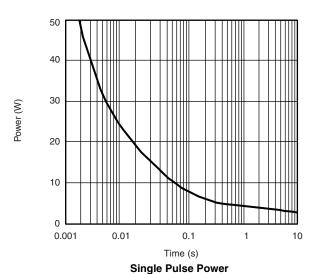
I_S - Source Current (A)

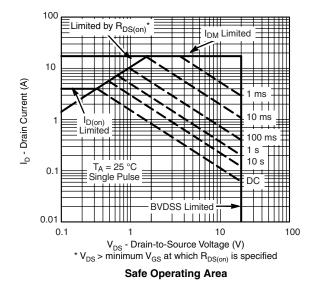
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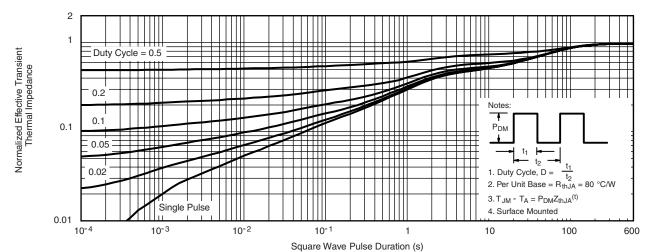
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





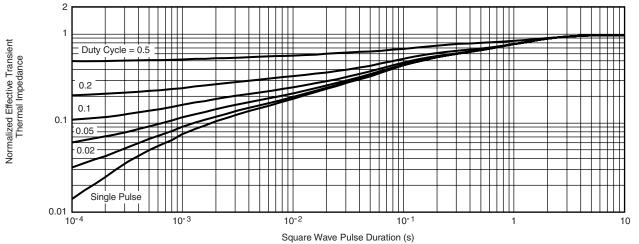




Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72755.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INC	HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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